## NSN 5961-00-556-1019

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-556-1019 **Inclosure Material:** Metal **Overall Length:** 0.370 inches **Terminal Length:** 1.125 inches **Overall Diameter:** 0.230 inches **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 reverse voltage, peak **Current Rating Per Characteristic:** 1.00 microamperes forward current, average peak **Power Rating Per Characteristic:** 150.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 80131-release1348 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

No Fiig: A110a0